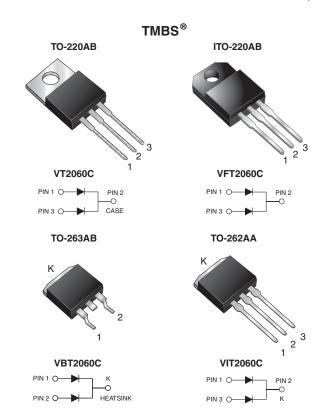
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Dual High Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.40 \text{ V}$ at $I_F = 5 \text{ A}$



PRIMARY CHARACTERISTICS							
I _{F(AV)}	2 x 10 A						
V _{RRM}	60 V						
I _{FSM}	150 A						
V _F at I _F = 10 A	0.52 V						
T _J max.	150 °C						
Package	TO-220AB, ITO-220AB, TO-263AB, TO-262AA						
Circuit configuration	Common cathode						

FEATURES





- · Low forward voltage drop, low power losses
- · High efficiency operation



- Meets MSL level 1, per J-STD-020, RoHS LF maximum peak of 245 °C (for TO-263AB compliant package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB, ITO-220AB, and TO-262AA package)
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB, and TO-262AA

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)								
PARAMETER		SYMBOL	VT2060C	VFT2060C	VBT2060C	VIT2060C	UNIT	
Maximum repetitive peak reverse voltage		V_{RRM}	60				V	
Maximum average few yeard restified average (fig. 1)	er device	_	20					
Maximum average forward rectified current (fig. 1)	er diode	I _{F(AV)}	10					
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I _{FSM}	150					
Non-repetitive avalanche energy at T _J = 25 °C, L = 60 mH per diode			120			mJ		
Peak repetitive reverse current at t_p = 2 μ s, 1 kHz, T_J = 38 °C \pm 2 °C			1.0			Α		
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min			1500			V		
Operating junction and storage temperature range			-55 to +150			°C		



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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT		
Breakdown voltage	I _R = 1.0 mA	T _A = 25 °C	V_{BR}	60 (minimum)	-	V		
Instantaneous forward voltage per diode (1)	I _F = 5 A	T _A = 25 °C		0.49	-	V		
	I _F = 10 A		V _F	0.57	0.65			
	I _F = 5 A	T _A = 125 °C		0.40	-			
	I _F = 10 A			0.52	0.59			
Reverse current per diode ⁽²⁾	V - 60 V	T _A = 25 °C	I _R	-	850	μΑ		
	$V_R = 60 \text{ V}$	T _A = 125 °C		14	40	mA		

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)								
PARAMETER		SYMBOL	VT2060C	VFT2060C VBT2060C VIT2060C			UNIT	
Typical thermal resistance	per diode	R _{θJC}	3.0	6.0	3.2	3.0	°C/W	
	per device		1.8	4.8	1.9	1.8	C/VV	

ORDERING INFORMATION (Example)								
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
TO-220AB	VT2060C-E3/4W	1.88	4W	50/tube	Tube			
ITO-220AB	VFT2060C-E3/4W	1.76	4W	50/tube	Tube			
TO-263AB	VBT2060C-E3/4W	1.39	4W	50/tube	Tube			
TO-263AB	VBT2060CE3/8W	1.39	8W	800/reel	Tape and reel			
TO-262AA	VIT2060C-E3/4W	1.45	4W	50/tube	Tube			

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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

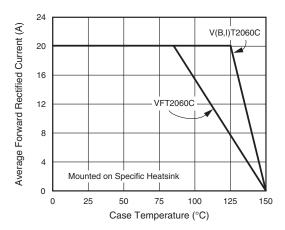


Fig. 1 - Maximum Forward Current Derating Curve

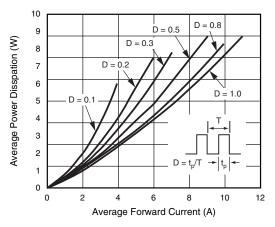


Fig. 2 - Forward Power Dissipation Characteristics Per Diode

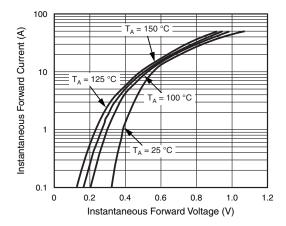


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

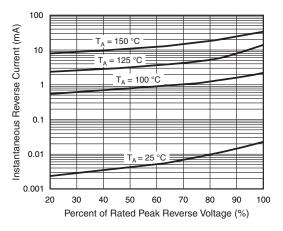


Fig. 4 - Typical Reverse Characteristics Per Diode

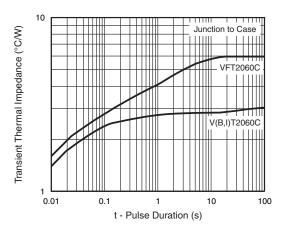


Fig. 5 - Typical Transient Thermal Impedance Per Diode

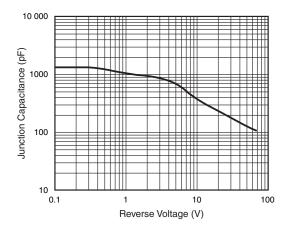


Fig. 6 - Typical Junction Capacitance Per Diode

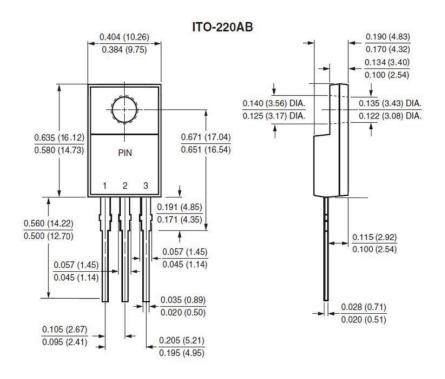


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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-220AB 0.415 (10.54) 0.380 (9.65) 0.185 (4.70) 0.161 (4.08) 0.175 (4.44) 0.139 (3.53) 0.055 (1.39) 0.113 (2.87) 0.045 (1.14) 0.103 (2.62) 0.603 (15.32) 0.635 (16.13) 0.573 (14.55) 0.625 (15.87) PIN 0.350 (8.89) 0.330 (8.38) 0.160 (4.06) 1.148 (29.16) 0.140 (3.56) 1.118 (28.40) 0.110 (2.79) 0.100 (2.54) 0.057 (1.45) 0.045 (1.14) 0.560 (14.22) 0.530 (13.46) 0.035 (0.90) 0.028 (0.70) 0.104 (2.65) 0.022 (0.56) 0.205 (5.20) 0.096 (2.45) 0.014 (0.36) 0.195 (4.95)

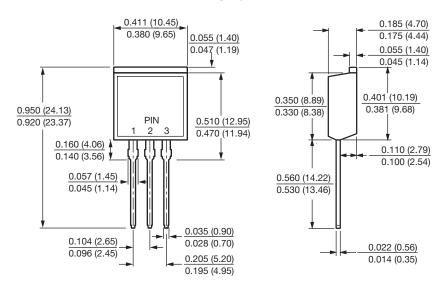




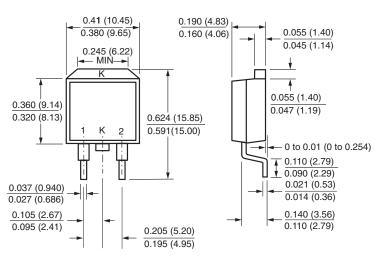
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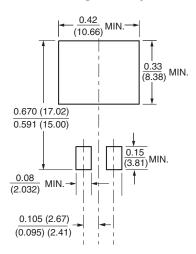
TO-262AA



TO-263AB



Mounting Pad Layout



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